DATA SHEET (Tentative)

Part No.	AN26031A
Package Code No.	ALGA005-W-0609ANA

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Contents

Overview	3
■ Features	3
Applications	3
■ Package	3
■ Туре	3
■ Application Circuit Example (Block Diagram)	4
• 2.5 GHz Band Application	4
• 3.5 GHz Band Application	5
■ Pin Descriptions	6
■ Absolute Maximum Ratings	7
■ Operating Supply Voltage Range	7
■ Allowable Voltage Range	8
Electrical Characteristics	9
■ Electrical Characteristics (Reference values for design)	11
Control Pin Mode Table	12
■ Truth Table	12
■ Technical Data	13
I/O block circuit diagrams and pin function descriptions	13
• $P_D - T_a$ diagram	14
■ Usage Note	15

AN26031A (Tentative) Single Band LNA-IC for 2.5 GHz Band Applications

Overview

- AN26031A is a single band LNA (Low Noise Amplifier)-IC for 2.5 GHz Band applications.
- Realizing high performance by using 0.18 μ m SiGeC Bi-CMOS process ($f_T = 90$ GHz, $f_{max} = 140$ GHz).

+3.0 V typ.

- High/Low Gain-mode is changeable, controlled by integrated CMOS logic circuit.
- Achieving miniaturization by using small size Wafer Level Chip Size Package (WLCSP).

Features

Low voltage operation

e i	51	
 Low current consumption 	7.5 mA typ.	(High-Gain mode)
	7.5 μA typ.	(Low-Gain mode)
• High gain	18.5 dB typ.	(High-Gain mode)
• Low noise figure	0.8 dB typ.	(High-Gain mode)
•Low distortion	+2.5 dBm typ.	(High-Gain mode)

•Small package

Applications

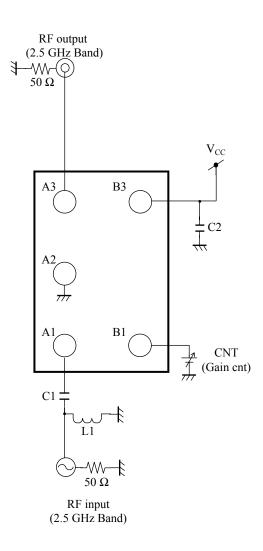
• 2.5 GHz Single Band LNA

Package

- 5 pin Wafer level chip size package (WLCSP) Size : 0.86 × 0.56 mm² (0.3 mm pitch)
- Туре
 - Bi-CMOS IC

- Application Circuit Example (Block Diagram)
 - 2.5 GHz Band Application

(Top View)

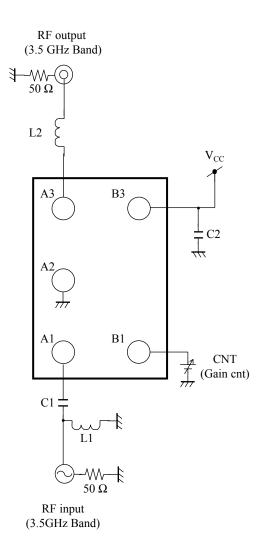


Notes) • This application circuit is an example. The operation of mass production set is not guaranteed. Perform enough evaluation and verification on the design of mass production set.

• This block diagram is for explaining functions. The part of the block diagram may be omitted, or it may be simplified.

- Application Circuit Example (Block Diagram) (continued)
 - 3.5 GHz Band Application

(Top View)



Notes) • This application circuit is an example. The operation of mass production set is not guaranteed. Perform enough evaluation and verification on the design of mass production set.

• This block diagram is for explaining functions. The part of the block diagram may be omitted, or it may be simplified.

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Descriptions

Pin No.	Pin name	Туре	Description
A1	IN	Input	RF input
A2	GND	Ground	GND
A3	OUT	Output	RF output
B1	CNT	Input	High-Gain/Low-Gain switch
B3	VCC	Power Supply	V _{CC}

Absolute Maximum Ratings

Note) Absolute maximum ratings are limit values which do not result in damages to this IC, and IC operation is not guaranteed at these limit values.

A No.	Parameter	Symbol	Rating	Unit	Notes
1	Supply voltage	V _{CC}	3.7	V	*1
2	Supply current	I _{CC}	18	mA	—
3	Power dissipation	P _D	29	mW	*2
4	Operating ambient temperature	T _{opr}	-40 to +85	°C	*3
5	Storage temperature	T _{stg}	-55 to +125	°C	*3

Notes) *1 :The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

*2 : The power dissipation shown is the value at $T_a = 75^{\circ}C$ for the independent (unmounted) IC package with a heat sink. When using this IC, refer to the $P_D^{-}T_a$ diagram of the package standard and design the heat radiation with sufficient margin so that the allowable value might not be exceeded based on the conditions of power supply voltage, load, and ambient temperature.

*3 : Except for the power dissipation, operating ambient temperature, and storage temperature, all ratings are for $T_a = 25^{\circ}C$.

Operating supply voltage range

Parameter	Symbol	Range	Unit	Notes
Supply voltage range	V _{CC}	2.7 to 3.6	V	*

Note) *: The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

Allowable Voltage Range

- Notes) Allowable current and voltage ranges are limit ranges which do not result in damages to this IC, and IC operation is not guaranteed within these limit ranges.
 - Voltage values, unless otherwise specified, are with respect to GND.
 - Do not apply external currents or voltages to any pin not specifically mentioned.
 - For the circuit currents, "+" denotes current flowing into the IC, and "-" denotes current flowing out of the IC.

Pin No.	Pin name	Rating	Unit	Note
A1	IN	—	V	*1
A3	OUT	-0.3 to V _{CC}	V	_
B1	CNT	-0.3 to V _{CC}	V	_

Note) *1 : RF signal input pin. Do not apply DC current. Do not apply more than 0 dBm to RF input.

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Electrical Characteristics at V_{CC} = 3.0 V

Note) $T_a = 25^{\circ}C \pm 2^{\circ}C$ unless otherwise specified.

B No.	Parameter	Symbol	Conditions	Limits			Unit	Note
B NO.	i didinotoi	Cymbol	Conditionio	Min	Тур	Max		Note
DC elec	DC electrical characteristics							
DC-1	Supply current HG	I _{CC} H	V_{CC} current at High-Gain mode No input signal		7.5	10	mA	
DC-2	Supply current LG	I _{CC} L	V _{CC} current at Low-Gain mode No input signal		7.5	15	μΑ	
DC-3	Input voltage (High-Gain mode)	VIH	_	1.48	_	3.6	V	Ι
DC-4	Input voltage (Low-Gain mode)	VIL	_	0	_	0.6	V	
DC-5	SW current (High)	IIH	Current at CNT pin VIH = V _{CC}	_	19	30	μA	_

\blacksquare Electrical Characteristics (continued) at V_{CC} = 3.0 V

Note) $T_a = 25^{\circ}C \pm 2^{\circ}C$, fRX = 2.5 GHz, PRX = -30 dBm, CW unless otherwise specified.

B No.	Parameter	Symbol	Conditions	Limits			Unit	Note
				Min	Тур	Max		-
AC elec	ctrical characteristics							
A-1	Power Gain HG	GHS	High-Gain mode	16.6	18.5	20	dB	—
A-2	Power Gain LG	GLS	Low-Gain mode	-8.8	-7	-5.2	dB	_
A-3	IIP3 –10 MHz offset HG	IIP3H1S	High-Gain mode f1 = fRX - 10 MHz f2 = fRX - 20 MHz Input 2 signals (f1, f2)	-2	2.5		dBm	

Electrical Characteristics (Reference values for design) at V_{CC} = 3.0 V

 Notes) T_a = 25°C±2°C, fRX = 2.3 GHz, 2.5 GHz, 2.7 GHz, PRX = -30 dBm, CW unless otherwise specified. The characteristics listed below are reference values derived from the design of the IC and are not guaranteed by inspection. If a problem does occur related to these characteristics, we will respond in good faith to user concerns.

B No.	Deremeter	Symbol	Conditions	Reference values			Unit	Note
D INU.	Parameter	Symbol	Conditions	Min	Тур	Max	Unit	note
AC elec	trical characteristics							
C-1	Power Gain HG	GHa	High-Gain mode	16.1	18.5	20.5	dB	—
C-2	Power Gain LG	GLa	Low-Gain mode PRX = -20 dBm	-9	-7	-5	dB	_
C-3	Noise Figure HG	NFHa	High-Gain mode	_	0.95	1.45	dB	*1
C-4	Noise Figure LG	NFLa	Low-Gain mode	_	7	9.5	dB	*1
C-5	IIP3 –10 MHz offset HG	IIP3H1a	$IIP3H1a \begin{array}{c} High-Gain mode \\ f1 = fRXa - 10 MHz \\ f2 = fRXa - 20 MHz \\ Input 2 signals (f1, f2) \end{array}$		2.5		dBm	
C-6	IIP3 +10 MHz offset HG	IIP3H2a	IIP3H2a High-Gain mode f1 = fRXa + 10 MHz f2 = fRXa + 20 MHz Input 2 signals (f1, f2)		2.0	_	dBm	_
C-7	Input P1dB HG	IP1dBHa	1dBHa High-Gain mode		-8.5	_	dBm	
C-8	IIP3 +100 kHz offset LG	IIP3La	3La Low-Gain mode f1 = fRXa f2 = fRXa + 100 kHz Input 2 signals (f1, f2)		24.5	_	dBm	
C-9	Input P1dB LG	IP1dBLa	Low-Gain mode	0	8	—	dBm	—
C-10	Reverse Isolation HG	ISOHa	High-Gain mode	26	31	_	dB	
C-11	Reverse Isolation LG	ISOLa	Low-Gain mode	4.5	7	—	dB	_
C-12	Input Return Loss HG	S11Ha	High-Gain mode	10	16		dB	
C-13	Input Return Loss LG	S11La	Low-Gain mode	7	8.5	_	dB	
C-14	Output Return Loss HG	S22Ha	High-Gain mode	10	19	_	dB	
C-15	Output Return Loss LG	S22La	Low-Gain mode	9.5	14.5		dB	_

Note) *1 : Connector & substrate loss (0.14 dB) included.

Control Pin Mode Table

Note) See parameters B No. DC-3 / B No. DC-4 in the Electrical Characteristics for control voltage retention ranges.

Pin No.	Description	Pin vo	oltage	Remarks
PIN NO.	Description	Low	High	Remarks
B1	High-Gain/Low-Gain Switching (Gain Control)	Low-Gain	High-Gain	_

Truth Table

Note) See parameters B No. DC-3 / B No. DC-4 in the Electrical Characteristics for control voltage retention ranges.

CNT	LNA	Mode
High	High-Gain	High-Gain
Low	Low-Gain	Low-Gain

Technical Data

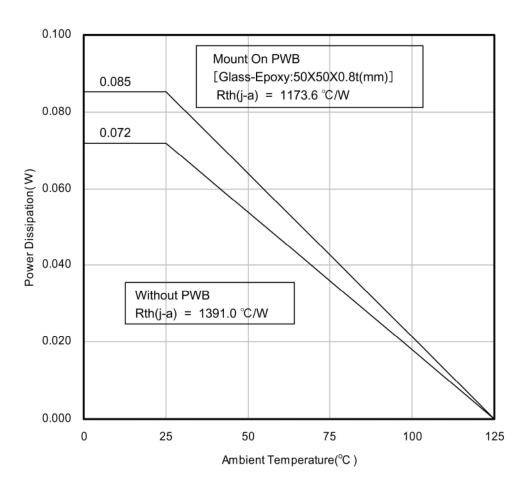
I/O block circuit diagram and pin function descriptions

Note) The characteristics listed below are reference values derived from the design of the IC and are not guaranteed.

Pin No.	Waveform and voltage	Internal circuit	Impedance	Description
Al	0.8 V	V _{cc}		LNA input
A2	0.0 V	_	_	GND
A3		V _{cc} A GND		LNA output
B1	_	(BI) (BI) (BI) (BI) (BI) (BI) (BI) (BI)	160 kΩ	High-Gain/Low-Gain SW input Less than 0.60 V : Low-Gain mode More than 1.48 V : High-Gain mode
В3	3.3 V	(B3) GND	_	Voltage supply

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- Technical Data (continued)
- $P_D T_a$ diagram



Usage Notes

- Special attention and precaution in using
 - 1. This IC is intended to be used for general electronic equipment [2.5 GHz Band Applications].
 - Consult our sales staff in advance for information on the following applications:
 - Special applications in which exceptional quality and reliability are required, or if the failure or malfunction of this IC may directly jeopardize life or harm the human body.
 - Any applications other than the standard applications intended.
 - (1) Space appliance (such as artificial satellite, and rocket)
 - (2) Traffic control equipment (such as for automobile, airplane, train, and ship)
 - (3) Medical equipment for life support
 - (4) Submarine transponder
 - (5) Control equipment for power plant
 - (6) Disaster prevention and security device
 - (7) Weapon
 - (8) Others : Applications of which reliability equivalent to (1) to (7) is required

It is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the IC described in this book for any special application, unless our company agrees to your using the IC in this book for any special application.

- 2. Pay attention to the direction of LSI. When mounting it in the wrong direction onto the PCB (printed-circuit-board), it might smoke or ignite.
- 3. Pay attention in the PCB (printed-circuit-board) pattern layout in order to prevent damage due to short circuit between pins. In addition, refer to the Pin Description for the pin configuration.
- 4. Perform a visual inspection on the PCB before applying power, otherwise damage might happen due to problems such as a solderbridge between the pins of the semiconductor device. Also, perform a full technical verification on the assembly quality, because the same damage possibly can happen due to conductive substances, such as solder ball, that adhere to the LSI during transportation.
- 5. Take notice in the use of this product that it might break or occasionally smoke when an abnormal state occurs such as output pin-VCC short (Power supply fault), output pin-GND short (Ground fault), or output-to-output-pin short (load short). And, safety measures such as an installation of fuses are recommended because the extent of the above-mentioned damage and smoke emission will depend on the current capability of the power supply.
- 6. When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
 Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure.

Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.

- 7. When using the LSI for new models, verify the safety including the long-term reliability for each product.
- 8. When the application system is designed by using this LSI, be sure to confirm notes in this book. Be sure to read the notes to descriptions and the usage notes in the book.
- 9. Due to unshielded structure of this IC, under exposure of light, function and characteristic of the product cannot be guaranteed. During normal operation or even under testing condition, please ensure that IC is not exposed to light.
- 10. Basically, chip surface is ground potential. Please design to ensure no contact between chip surface and metal shielding.

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(6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.

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